

## Light Emitting Diode(InGaAlP/InGaN)

# KLP-34RG-X-X

KLP-34RG has a high bright InGaAlP red LED and a high bright InGaN green LED.

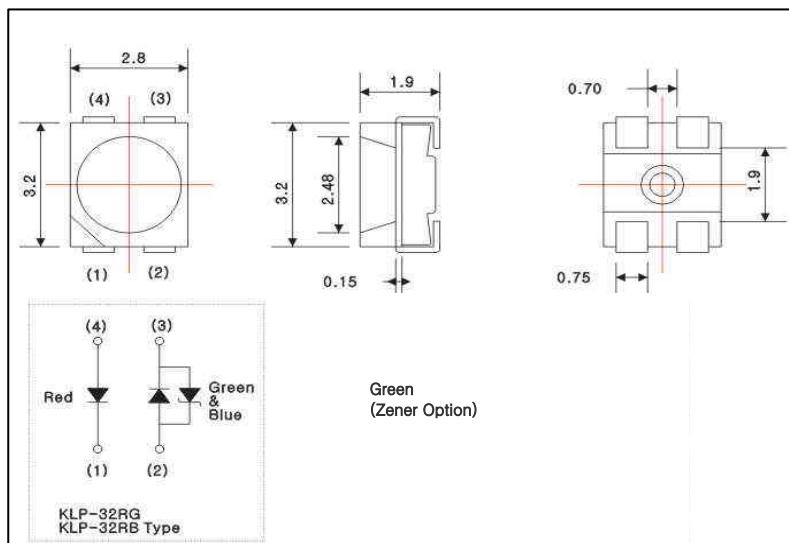
### Features

- Transparent epoxy Encapsulent
- High Optical Output

### Applications

- Display
- Indicator
- Signage

### DIMENSIONS



### Maximum Ratings

[ Ta=25°C ]

Parameter	Symbol	Ratings	Unit
Reverse Voltage (w/o Zener)	V <sub>R</sub>	5	V
Reverse current ( w Zener)	I <sub>R</sub>	50	mA
Forward current	I <sub>F</sub>	30	mA
Pulse forward current <sup>*1</sup>	I <sub>FP</sub>	0.1	A
Power dissipation	P <sub>D</sub>	180	mW
Operating temperature	T <sub>opr.</sub>	-30 ~ +85	°C
Storage temperature	T <sub>stg.</sub>	-40 ~ +105	°C
Soldering Temperature <sup>*2</sup>	T <sub>sol.</sub>	260	°C

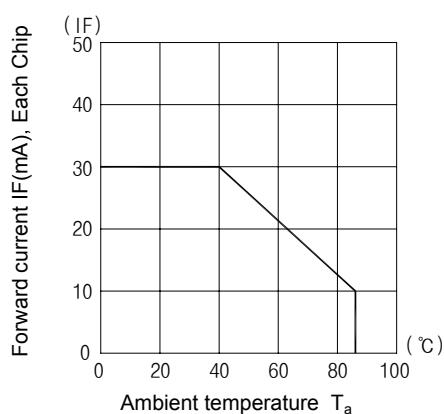
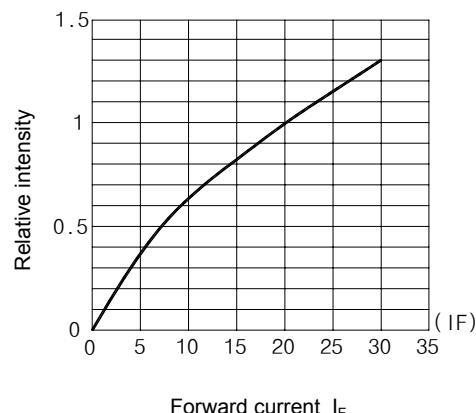
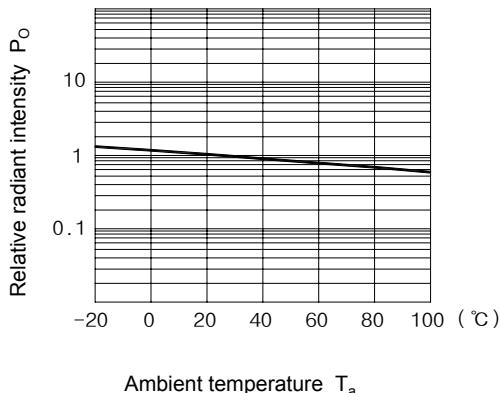
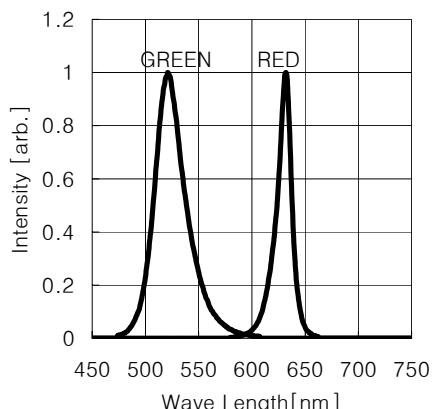
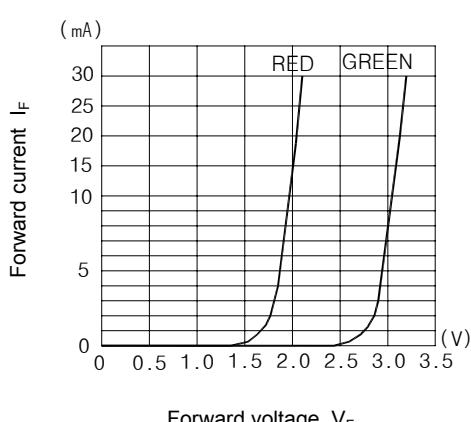
\*1. I<sub>FP</sub> Measured under duty £ 1/10 @ 1KHz

\*2. Soldering time £ 5 Sec

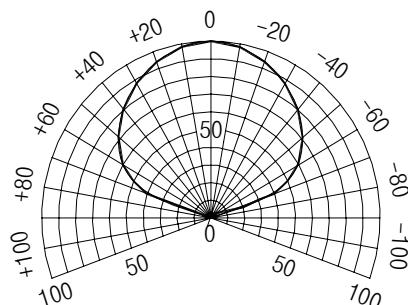
### Electro-Optical Characteristics

[ Ta=25°C ]

Parameter	Symbol	Conditions	Min	Typ	Max	Unit	
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 20 mA	R	-	2.0	2.5	
			G		3.3	3.9	
Optical Output Power	P <sub>O</sub>	I <sub>F</sub> = 20 mA	R	4.00	5.50	-	
			G	3.50	5.00		
	I <sub>v</sub>		R	300	350	-	
			G	650	750		
Peak emission wavelength	λ <sub>P</sub>	I <sub>F</sub> = 20 mA	R	-	630	-	
			G	-	520	-	
Dominant Wave Length	λ <sub>d</sub>	I <sub>F</sub> = 20 mA	R	620	-	635	
			G	515	-	535	
Spectral half bandwidth	Δλ	I <sub>F</sub> = 20 mA	R	-	20	-	
			G	-	30	-	
Half angle	ΔΘ	I <sub>F</sub> = 20 mA	-	120	-	deg.	

**KLP-34RG-X-X****Forward current vs.  
Ambient temperature****Radiant Intensity vs.  
Forward current****Relative radiant intensity vs.  
Ambient temperature****Relative intensity vs.  
Wavelength****Forward current Vs.  
Forward voltage****Radiant Pattern**

Angle(deg)



Relative intensity(%)